# NSN 5962-01-308-4195

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## Body Length:

1.290 inches

## Body Width:

Between 0.500 inches and 0.610 inches

## **Body Height:**

Between 0.150 inches and 0.210 inches

## **Maximum Power Dissipation Rating:**

635.0 milliwatts

#### **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

## Storage Tempurature Range:

-65.0/+150.0 degrees celsius

## End Application:

2835-01-016-6226 circuit card as

#### **Features Provided:**

Hermetically sealed and burn in and ultraviolet erasable and programmed and w/enable and electrostatic sensitive

#### Inclosure Material:

Ceramic

#### **Inclosure Configuration:**

Dual-in-line

## Output Logic Form:

N-type metal oxide-semiconductor logic

#### **Input Circuit Pattern:**

13 input

## Case Outline Source And Designator:

D-3 mil-m-38510

## **Terminal Surface Treatment:**

Solder

## Voltage Rating And Type Per Characteristic:

-0.3 volts power source and 6.0 volts power source

## **Time Rating Per Chacteristic:**

450.00 nanoseconds propagation delay time, low to high level output and 450.00 nanoseconds propagation delay time, high to low level

output

#### Memory Device Type:

Rom

#### **Memory Capacity:**

Unknown

#### **Test Data Document:**

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

## Terminal Type And Quantity:

24 printed circuit

#### Shelf Life:

N/a

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Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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